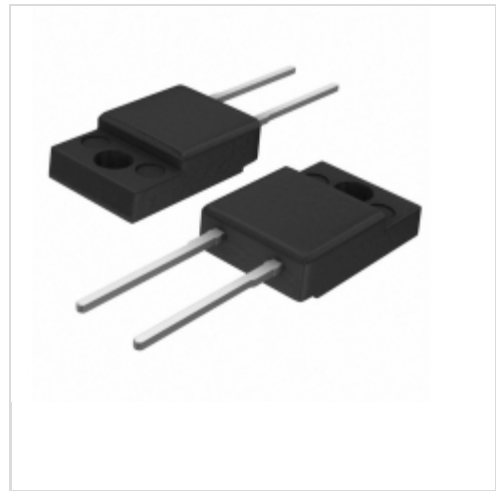


**BYV29F-300HE3/45**



Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 300V 8A ITO220AC

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Discrete Semiconductor Products

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Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

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**1**

Confirm the product

**2**

submit the order

**3**

payment

**4**

wait for delivery

**5**

receive the goods

Specifications

|   |                                  |
|---|----------------------------------|
| <b>Voltage - Forward (Vf) (Max) @ If:</b> | 1.25V @ 8A                       |
| <b>Voltage - DC Reverse (Vr) (Max):</b>   | 300V                             |
| <b>Supplier Device Package:</b>           | ITO-220AC                        |
| <b>Speed:</b>                             | Fast Recovery = 200mA (Io)       |
| <b>Series:</b>                            | -                                |
| <b>Reverse Recovery Time (trr):</b>       | 50ns                             |
| <b>Packaging:</b>                         | Tube                             |
| <b>Package / Case:</b>                    | TO-220-2 Full Pack, Isolated Tab |
| <b>Operating Temperature - Junction:</b>  | -40°C ~ 150°C                    |
| <b>Mounting Type:</b>                     | Through Hole                     |
| <b>Diode Type:</b>                        | Standard                         |
| <b>Current - Reverse Leakage @ Vr:</b>    | 10µA @ 300V                      |
| <b>Current - Average Rectified (Io):</b>  | 8A                               |
| <b>Capacitance @ Vr, F:</b>               | -                                |

Related products



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DIODE GEN PURP 600V 9A TO220AC  
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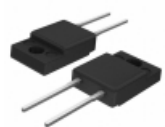
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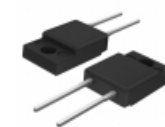
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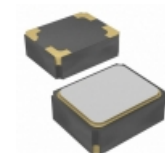
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